

**2SK2623**

Ultrahigh-Speed Switching Applications

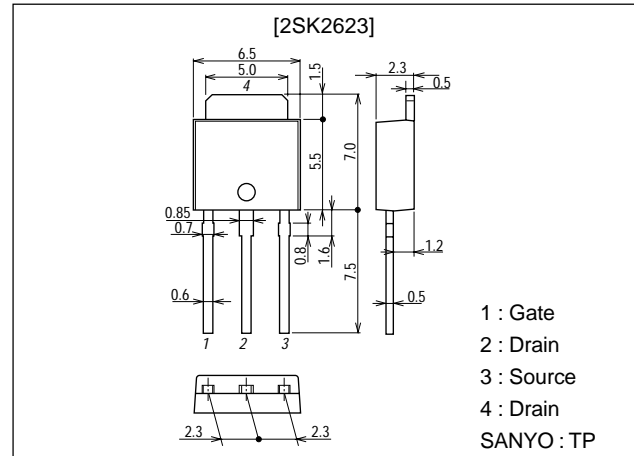
Features

- Low ON-resistance.
- Low Qg.

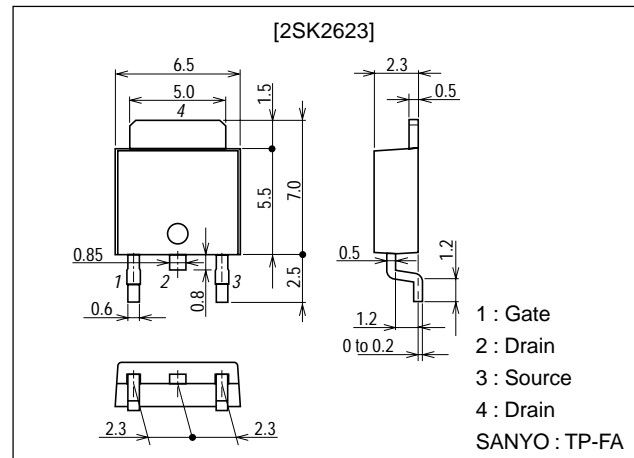
Package Dimensions

unit:mm

2083B



2092B



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Specifications

Absolute Maximum Ratings at Ta = 25°C

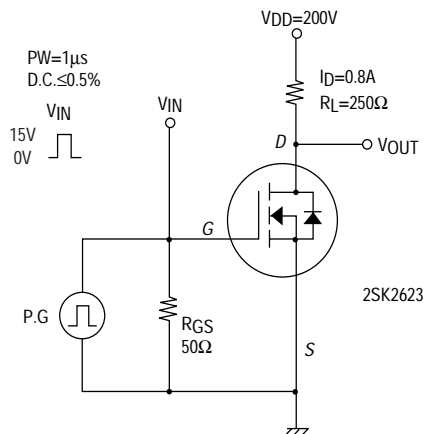
Parameter	Symbol	Conditions	Ratings	Unit
Drain-to-Source Voltage	V_{DSS}		600	V
Gate-to-Source Voltage	V_{GSS}		±30	V
Drain Current (DC)	I_D		1.5	A
Drain Current (Pulse)	I_{DP}		6	A
Allowable Power Dissipation	P_D		1.0	W
		$T_c=25^\circ\text{C}$	30	W
Channel Temperature	T_{ch}		150	°C
Storage Temperature	T_{stg}		-55 to +150	°C

Electrical Characteristics at Ta = 25°C

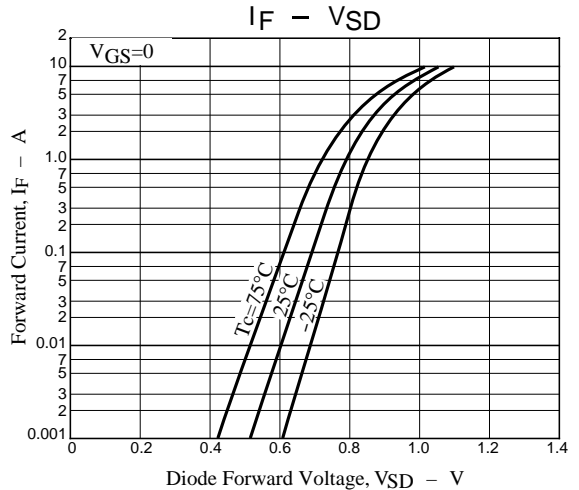
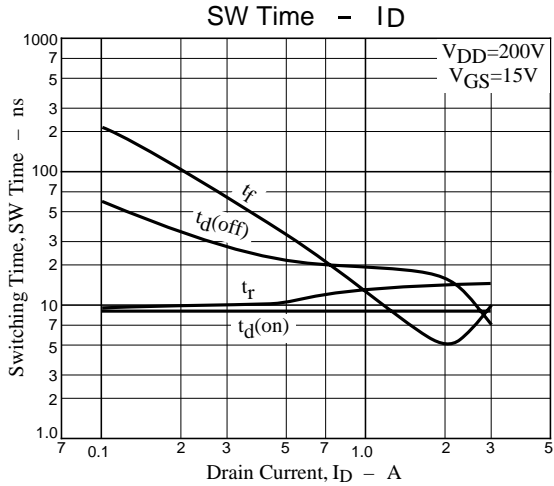
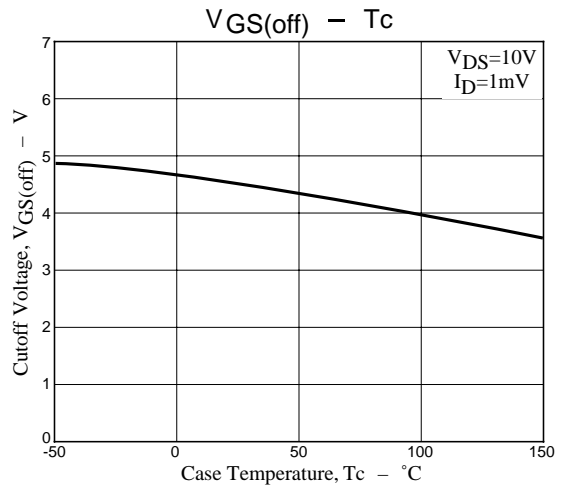
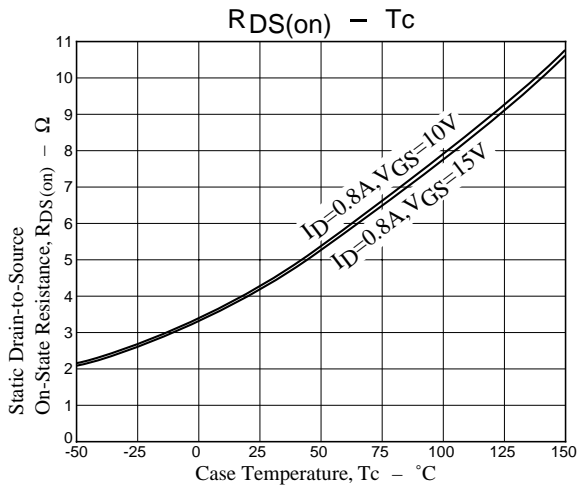
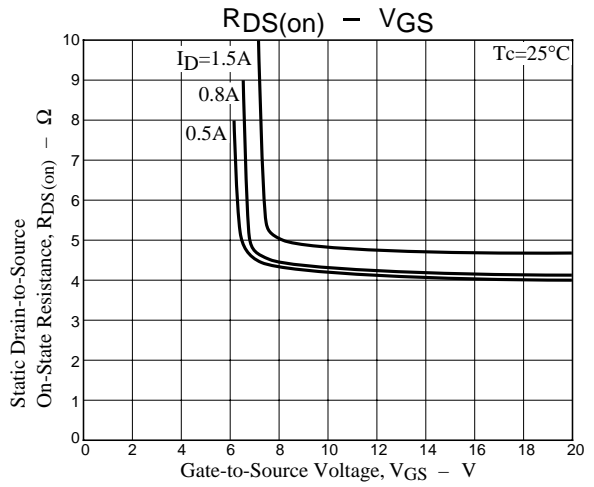
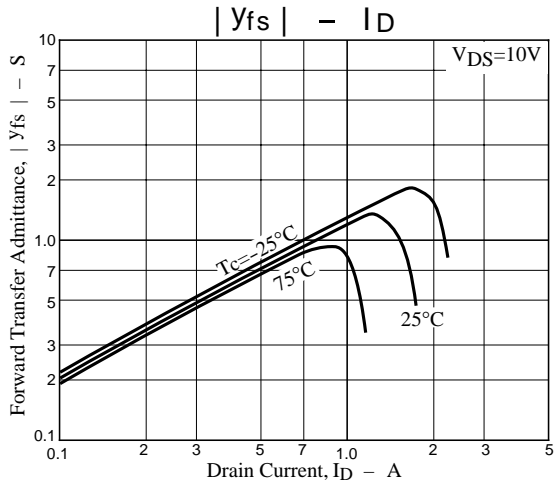
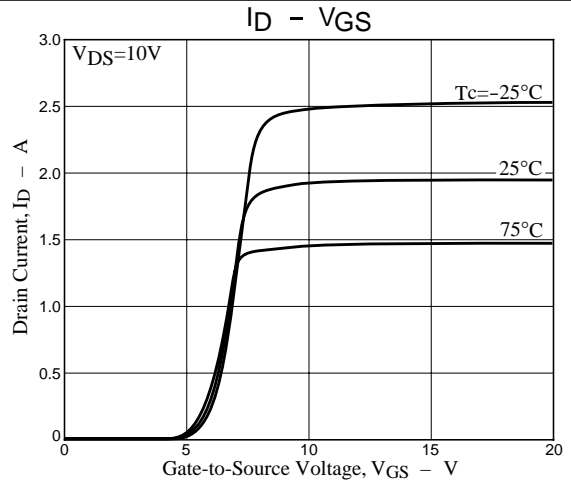
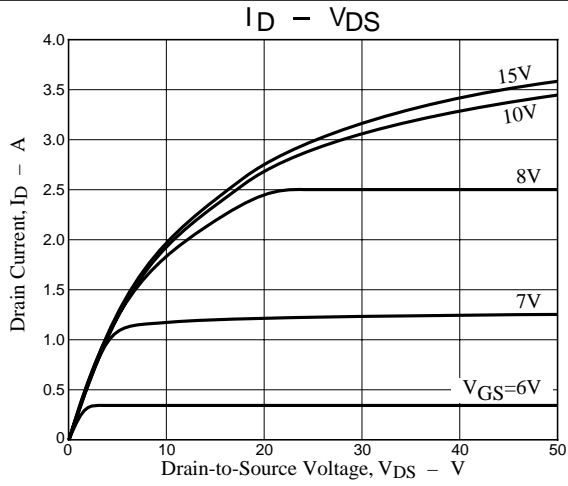
Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	
Drain-to-Source Breakdown Voltage	$V_{(BR)DSS}$	$I_D=1\text{mA}, V_{GS}=0$	600			V
Zero-Gate Voltage Drain Current	I_{DSS}	$V_{DS}=600\text{V}, V_{GS}=0$			1.0	mA
Gate-to-Source Leakage Current	I_{GSS}	$V_{GS}=\pm 30\text{V}, V_{DS}=0$			±100	nA
Cutoff Voltage	$V_{GS(off)}$	$V_{DS}=10\text{V}, I_D=1\text{mA}$	3.5		5.5	V
Forward Transfer Admittance	$ y_{fs} $	$V_{DS}=10\text{V}, I_D=0.8\text{A}$	0.5	1.0		S
Static Drain-to-Source On-State Resistance	$R_{DS(on)}$	$V_{GS}=15\text{V}, I_D=0.8\text{A}$		4.2	5.5	Ω
Input Capacitance	C_{iss}	$V_{DS}=20\text{V}, f=1\text{MHz}$		300		pF
Output Capacitance	C_{oss}	$V_{DS}=20\text{V}, f=1\text{MHz}$		90		pF
Reverse Transfer Capacitance	C_{rss}	$V_{DS}=20\text{V}, f=1\text{MHz}$		45		pF
Total Gate Charge	Q_g	$V_{DS}=200\text{V}, V_{GS}=10\text{V}, I_D=1.5\text{A}$		8		nC
Turn-ON Delay Time	$t_{d(on)}$	See specified Test Circuit		9		ns
Rise Time	t_r	See specified Test Circuit		12		ns
Turn-OFF Delay Time	$t_{d(off)}$	See specified Test Circuit		20		ns
Fall Time	t_f	See specified Test Circuit		17		ns
Diode Forward Voltage	V_{SD}	$I_S=1.5\text{A}, V_{GS}=0$		0.8	1.2	V

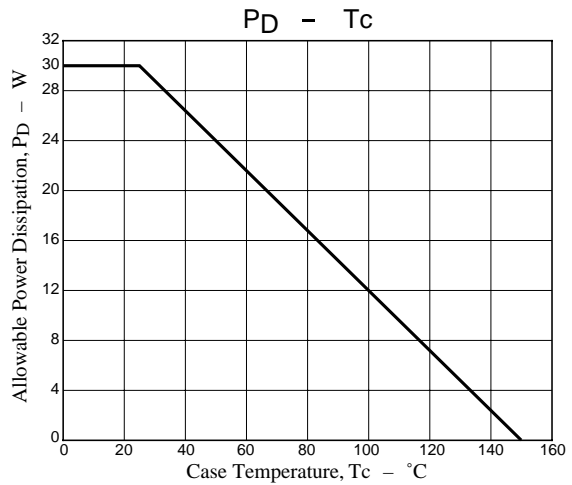
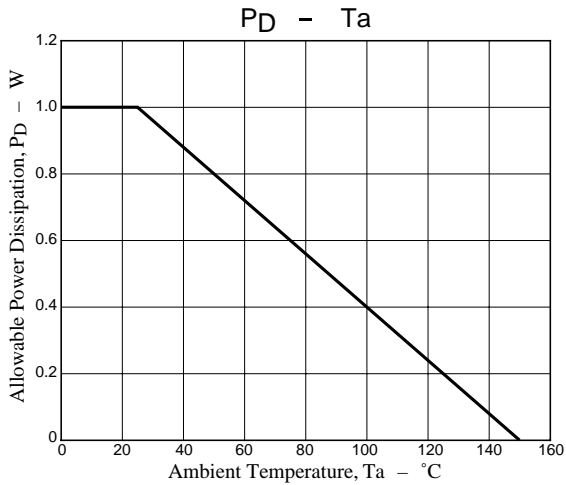
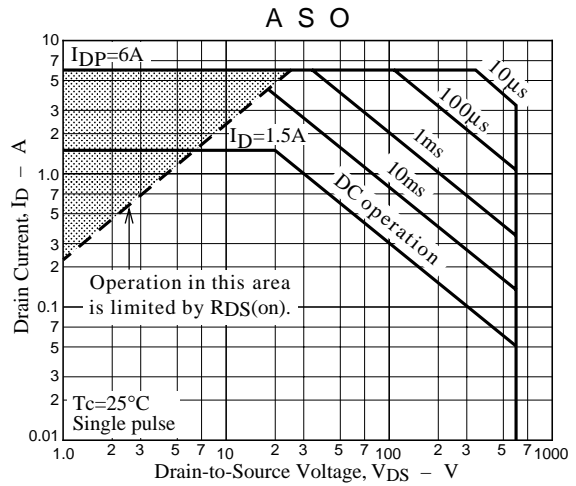
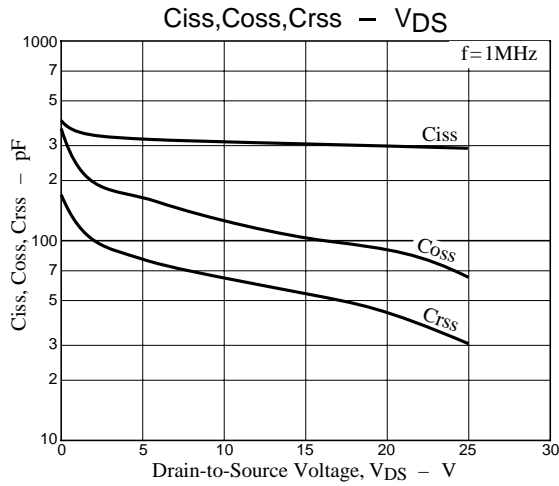
Marking : K2623

Switching Time Test Circuit



2SK2623





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